

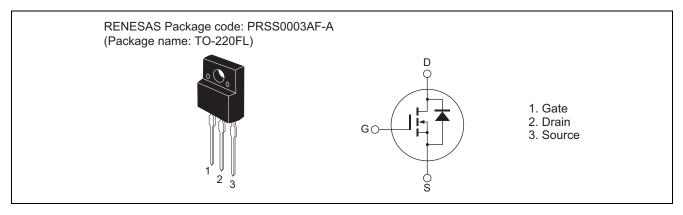
Silicon N Channel MOS FET High Speed Power Switching

R07DS0422EJ0100 Rev.1.00 May 26, 2011

Features

- Low on-resistance
- $R_{DS(on)} = 1.35 \ \Omega \text{ typ.}$ (at $I_D = 3 \text{ A}$, $V_{GS} = 10 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

-			(14 - 25 C)
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	500	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	ID ^{Note4}	6	А
Drain peak current	Note1 I _{D (pulse)}	18	А
Body-drain diode reverse drain current	I _{DR}	6	А
Body-drain diode reverse drain peak current	Note1 I _{DR (pulse)}	18	А
Avalanche current	I _{AP} ^{Note3}	4	А
Avalanche energy	E _{AR} ^{Note3}	0.88	mJ
Channel dissipation	Pch Note2	28.5	W
Channel to case thermal impedance	θch-c	4.38	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. $PW \leq 10~\mu s,~duty~cycle \leq 1\%$

2. Value at Tc = 25°C

- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C
- 4. Limited by maximum safe operation area



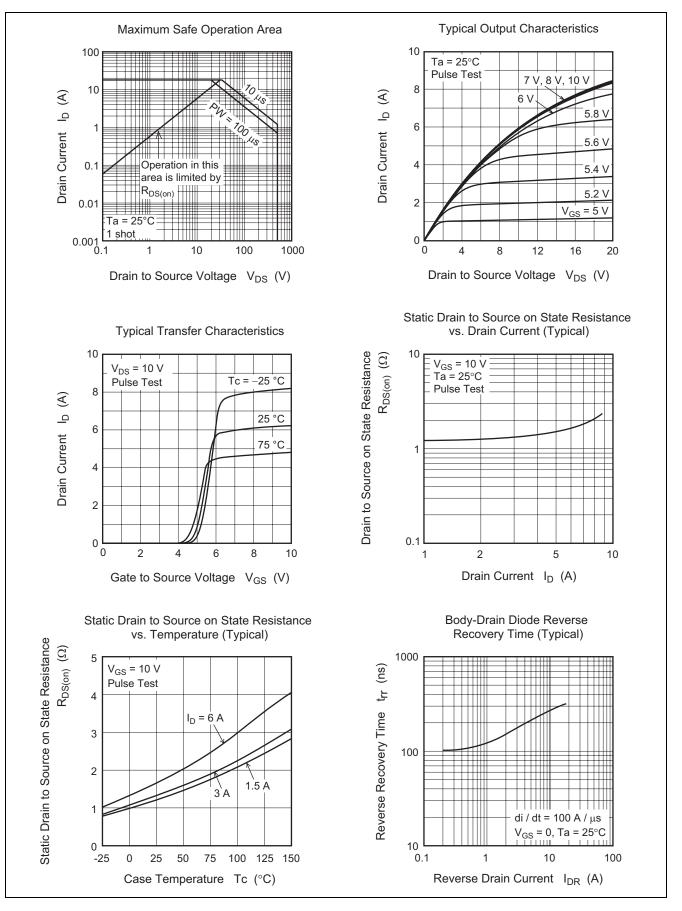
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	500			V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}			1	μΑ	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS}=\pm 30~V,~V_{DS}=0$
Gate to source cutoff voltage	V _{GS(off)}	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	1.35	1.70	Ω	$I_D = 3 \text{ A}, V_{GS} = 10 \text{ V}^{Note5}$
resistance						
Input capacitance	Ciss		440		pF	V _{DS} = 25 V
Output capacitance	Coss		52	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss		7	—	pF	
Turn-on delay time	t _{d(on)}	_	26	_	ns	I _D = 3 A
Rise time	tr	_	19		ns	$V_{GS} = 10 V$ $R_L = 83.3 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t _{d(off)}	_	50		ns	
Fall time	t _f	_	14		ns	
Total gate charge	Qg	_	14		nC	V _{DD} = 400 V
Gate to source charge	Qgs	_	2.5		nC	V _{GS} = 10 V I _D = 6 A
Gate to drain charge	Qgd	_	6.9		nC	
Body-drain diode forward voltage	V _{DF}		0.95	1.50	V	$I_F = 6 A, V_{GS} = 0^{Note5}$
Body-drain diode reverse recovery time	t _{rr}	_	230		ns	$I_F = 6 A, V_{GS} = 0$
						di _F /dt = 100 A/µs

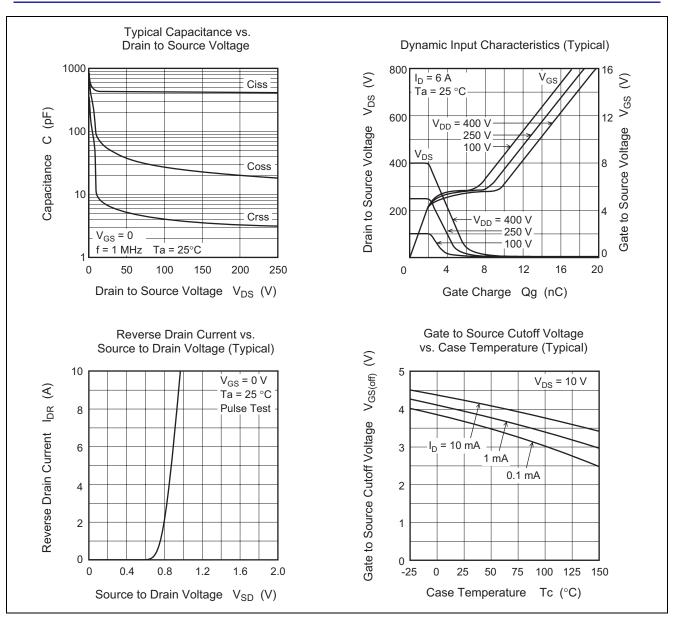
Notes: 5. Pulse test



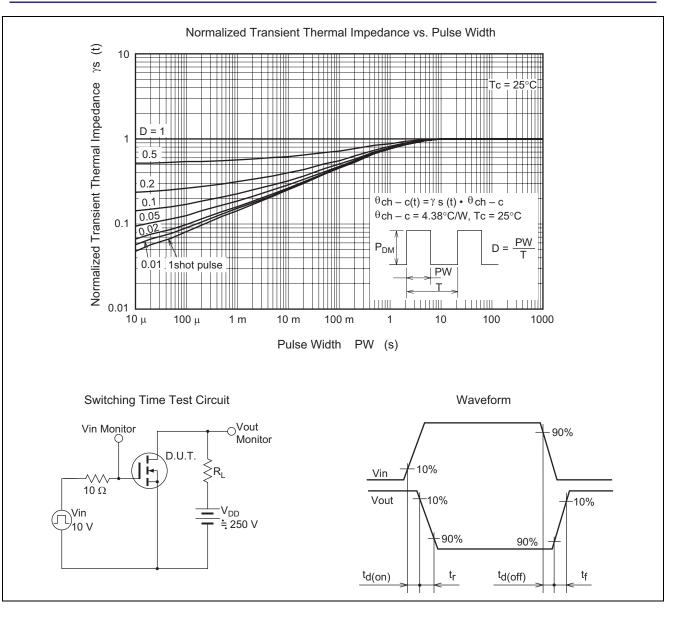
Main Characteristics





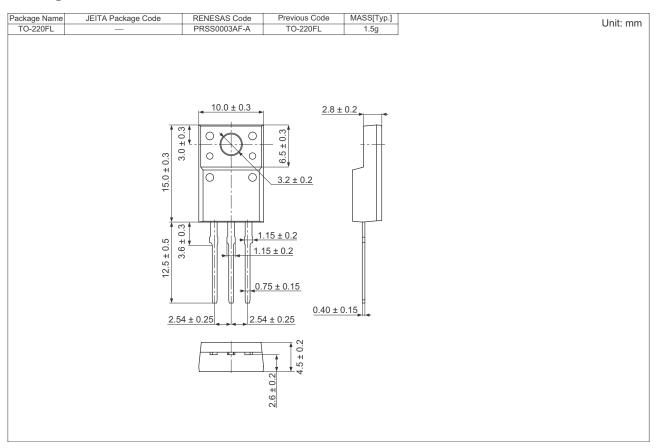








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK5026DPP-M0-T2	600 pcs	Box (Tube)



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